



DC COMPONENTS CO., LTD.

RECTIFIER SPECIALISTS

**DB151
THRU
DB157**

TECHNICAL SPECIFICATIONS OF SINGLE-PHASE SILICON BRIDGE RECTIFIER

VOLTAGE RANGE - 50 to 1000 Volts

CURRENT - 1.5 Ampere

FEATURES

- * Good for automation insertion
- * Surge overload rating - 50 Amperes peak
- * Ideal for printed circuit board
- * Reliable low cost construction
- * Glass passivated junction

MECHANICAL DATA

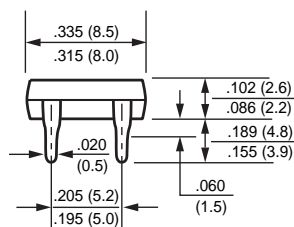
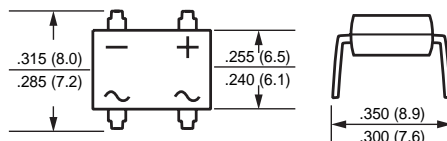
- * Case: Molded plastic
- * Epoxy: UL 94V-0 rate flame retardant
- * Lead: MIL-STD-202E, Method 208 guaranteed
- * Polarity: Symbols molded or marked on body
- * Mounting position: Any
- * Weight: 0.4 gram

MAXIMUM RATINGS AND ELECTRICAL CHARACTERISTICS

Ratings at 25 °C ambient temperature unless otherwise specified.
Single phase, half wave, 60 Hz, resistive or inductive load.
For capacitive load, derate current by 20%.



DB-1



Dimensions in inches and (millimeters)

	SYMBOL	DB151	DB152	DB153	DB154	DB155	DB156	DB157	UNITS
Maximum Recurrent Peak Reverse Voltage	V _{RRM}	50	100	200	400	600	800	1000	Volts
Maximum RMS Bridge Input Voltage	V _{RMS}	35	70	140	280	420	560	700	Volts
Maximum DC Blocking Voltage	V _{DC}	50	100	200	400	600	800	1000	Volts
Maximum Average Forward Output Current at TA = 40°C	I _O	1.5							Amps
Peak Forward Surge Current 8.3 ms single half sine-wave superimposed on rated load (JEDEC Method)	I _{FSM}	60							Amps
Maximum Forward Voltage Drop per element at 1.0A DC	V _F	1.1							Volts
Maximum DC Reverse Current at Rated DC Blocking Voltage per element	@TA = 25°C	10							uAmps
	@TA = 125°C	500							
I ² t Rating for Fusing (t<8.3ms)	I ² t	10							A ² Sec
Typical Junction Capacitance (Note1)	C _J	25							pF
Typical Thermal Resistance (Note 2)	RθJA	40							°C/W
Operating and Storage Temperature Range	T _{J,TSTG}	-65 to + 150							°C

NOTES : 1. Measured at 1 MHz and applied reverse voltage of 4.0 volts

2. Thermal Resistance from Junction to Ambient and from junction to lead mounted on P.C.B. with 0.5 x 0.5" (13x13mm) copper pads.